Supporting Information

Electrocatalytic activity of NiO on silicon nanowires with a carbon shell and its application to dye-sensitized solar cell counter electrodes

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J-V curve scanning detail.

The JV scanning was performed at forward scanning direction, starting from 0.08 V to V_{oc} . The voltage step is 3 mV and interval time is 50 msec. Total points are around 250 depending on V_{oc} .



Figure S1. Transmission electron microscopy micrographs of a SiNW/C@NiO, and energy dispersive spectroscopy elemental mapping images of Si, Ni, O, and C.



Figure S2. Electrochemical impedance spectroscopy for full dye-sensitized solar cells using Pt, SiNW/C, and NiO@SiNW/C as the counter electrodes.

Table S1. Photovoltaic parameters of dye-sensitized solar cells based on FTO/Pt, SiNW/C, and NiO@SiNW/C counter electrodes measured under AM1.5G illumination and electrochemical impedance spectroscopy parameters fitted from the equivalent circuit.

Counter	V _{oc}	J _{sc}	FF	ŋ	R _s ^{a)}	R _{ct} ^{a)}	$Z_n^{a)}$
Electrode	[V]	[mA/cm ²]	[%]	[%]	$[\Omega \cdot cm^2]$	$[\Omega \cdot cm^2]$	$[\Omega \cdot cm^2]$
FTO/Pt	0.762	16.55	68.4	8.62	0.60	0.46	0.27
SiNW/C	0.744	17.68	65.9	8.67	0.17	0.23	0.29
NiO@SiNW/C	0.759	18.52	67.5	9.49	0.19	0.07	0.25

^{a)} Obtained from symmetric cells



Figure S3. Cyclic voltammetry curves of FTO/Pt, SiNW/C, and NiO@SiNW/C electrodes in 5×10^{-3} M K₃Fe(CN)₆/ 0.1 M KCl solution at scan rate of 50 mV s⁻¹.

Table S2. Calculated electroactive surface area values of FTO/Pt, SiNW/C, and NiO@SiNW/C electrodes.

Counter	FTO/Pt	SiNW/C	NiO@SiNW/C	
Electrode			_	
A (cm^2)	2.132	3.391	4.290	

The tested area is $1.0 \times 1.5 \text{ cm}^2$.



Figure S4. The incident photon-to-current conversion efficiencies(IPCEs) spectra for FTO/Pt, SiNW/C, and NiO@SiNW/C electrodes.



Figure S5. Raman spectra for SiNW/C and NiO@SiNW/C.

Table S2. Peak positions of D and G bands and I_D/I_G ratios.

	D band (cm ⁻¹)	G band (cm ⁻¹)	I_D/I_G
NiO@SiNW/C	1343	1599	1.58
SiNW/C	1343	1599	1.71